

Vishay Semiconductors



Small Signal Switching Diode, Dual

Features

- Silicon Epitaxial Planar Diode
- Fast switching dual diode with common anode
- This diode is also available in other configurations including: a single with type designation BAL99, a dual anode to cathode with type designation BAV99, and a dual common cathode with type designation BAV70.
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Mechanical Data

Case: SOT-23

Weight: approx. 8.8 mg

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Parts Table

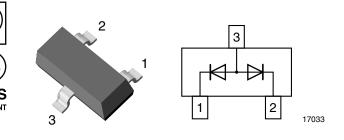
Part	Ordering code	Marking	Remarks
BAW56-V	BAW56-V-GS18 or BAW56-V-GS08	JD	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage = Working peak reverse voltage = DC Blocking voltage		V _R = V _{RRM}	70	V	
Forward continuous current		١ _F	250	mA	
Non repetitive peak forward current	t _p = 1 μs	I _{FSM}	2	А	
	t _p = 1 ms	I _{FSM}	1	А	
	t _p = 1 s	I _{FSM}	0.5	A	
Power dissipation		P _{tot}	350 ¹⁾	mW	

¹⁾ Device on fiberglass substrate, see layout



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Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambiant air		R _{thJA}	430	K/W
Junction temperature		Тj	150	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

¹⁾ Device on fiberglass substrate, see layout

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 1 mA	V _F			715	mV
	I _F = 10 mA	V _F			855	mV
	I _F = 50 mA	V _F			1000	mV
	I _F = 150 mA	V _F			1250	mV
Reverse current	V _R = 70 V	I _R			2.5	μA
	V _R = 70 V, T _j = 150 °C	I _R			100	μA
	V _R = 25 V, T _j = 150 °C	I _R			30	μA
Diode capacitance	V _F = V _R = 0, f = 1 MHz	CD			2	pF
Reverse recovery time	$I_F = 10 \text{ mA to } I_R = 1 \text{ mA},$ $V_R = 6 \text{ V}, \text{ R}_L = 100 \Omega$	t _{rr}			6	ns

Typical Characteristics T_{amb} = 25 °C, unless otherwise specified

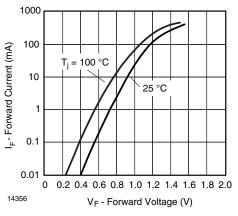


Figure 1. Forward Current vs. Forward Voltage

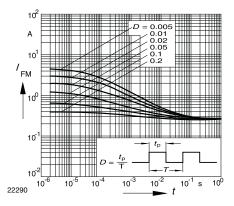


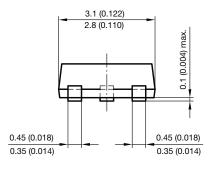
Figure 2. Peak forward current $I_{FM} = f(t_p)$

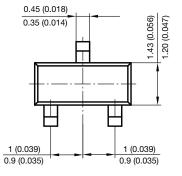


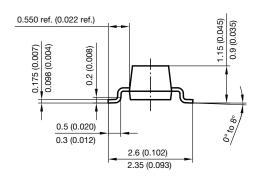
BAW56-V

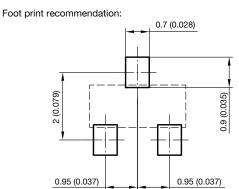
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Package Dimensions in millimeters (inches): SOT-23









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